# RENESAS

# HD74ALVC2G06

Triple Inverter Buffers / Drivers with Open Drain

REJ03D0162-0500 Rev.5.00 Sep 08, 2006

### Description

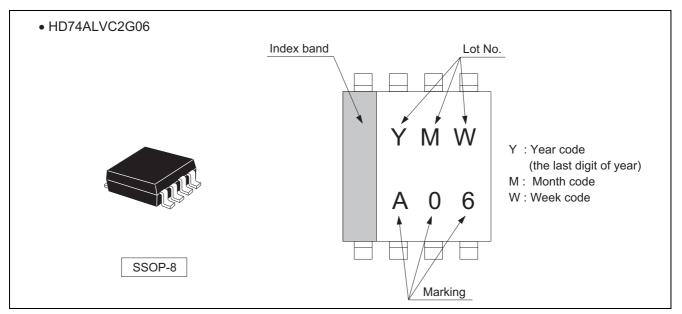
The HD74ALVC2G06 has triple inverter buffers / drivers with open drain outputs in an 8 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

### Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.2 to 3.6 V
- Operating temperature range: -40 to  $+85^{\circ}$ C
- All inputs  $V_{IH}$  (Max.) = 3.6 V (@V<sub>CC</sub> = 0 V to 3.6 V)
- All outputs  $V_0$  (Max.) = 3.6 V (@V<sub>CC</sub> = 0 V, Output: Z)
- Output current  $2 \text{ mA} (@V_{CC} = 1.2 \text{ V})$ 
  - $4 \text{ mA} (@V_{CC} = 1.4 \text{ V to } 1.6 \text{ V})$   $6 \text{ mA} (@V_{CC} = 1.65 \text{ V to } 1.95 \text{ V})$   $18 \text{ mA} (@V_{CC} = 2.3 \text{ V to } 2.7 \text{ V})$  $24 \text{ mA} (@V_{CC} = 3.0 \text{ V to } 3.6 \text{ V})$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74ALVC2G06USE	SSOP-8 pin	PVSP0008KA-A (TTP-8DBV)	US	E (3,000 pcs/reel)

# **Outline and Article Indication**





## **Function Table**

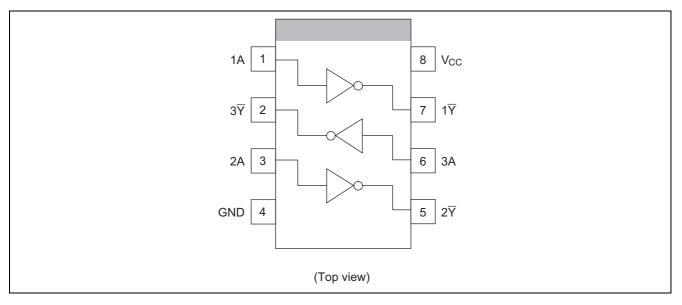
Input A	Output <b>Y</b>				
L	Z				
Н	L				

H: High level

L: Low level

Z: High impedance

# **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	Vcc	-0.5 to 4.6	V	
Input voltage range <sup>*1</sup>	Vi	-0.5 to 4.6	V	
Output voltage range *1, 2	Vo	–0.5 to V <sub>CC</sub> +0.5	v	Output : L
	vo	-0.5 to 4.6	v	V <sub>CC</sub> : OFF or Output : Z
Input clamp current	I <sub>IK</sub>	-50	mA	V <sub>1</sub> < 0
Output clamp current	Ι <sub>ΟΚ</sub>	-50	mA	V <sub>0</sub> < 0
Continuous output current	lo	±50	mA	$V_{O} = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±100	mA	
Maximum power dissipation at Ta = $25^{\circ}$ C (in still air) <sup>*3</sup>	PT	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 4.6 V maximum.

3. The maximum package power dissipation was calculated using a junction temperature of 150°C.



# **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	1.2	3.6	V	
Input voltage range	VI	0	3.6	V	
Output voltage range	Vo	0	V <sub>CC</sub>	V	
		—	2		V <sub>CC</sub> = 1.2 V
		—	4		$V_{CC} = 1.4 V$
Output current	I <sub>OL</sub>	—	6	mA	V <sub>CC</sub> = 1.65 V
		—	18		V <sub>CC</sub> = 2.3 V
		—	24		$V_{CC} = 3.0 V$
Input transition rise or fall rate	Δt / Δv	0	20	ns/V	$V_{CC}$ = 1.2 to 2.7 V
	$\Delta t / \Delta V$	0	10	115/V	V <sub>CC</sub> = 3.3±0.3 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

# **Electrical Characteristics**

 $(Ta = -40 \text{ to } 85^{\circ}C)$ 

ltem	Symbol	V <sub>cc</sub> (V) <sup>*1</sup>	Min	Тур	Max	Unit	Test Conditions
		1.2	V <sub>CC</sub> ×0.75				
		1.4 to 1.6	V <sub>CC</sub> ×0.7		_		
	V <sub>IH</sub>	1.65 to 1.95	V <sub>CC</sub> ×0.7	_	—		
		2.3 to 2.7	1.7				
Input voltage		3.0 to 3.6	2.0		_	V	
input voltage		1.2	—		V <sub>CC</sub> ×0.25	v	
		1.4 to 1.6	—		V <sub>CC</sub> ×0.3		
	VIL	1.65 to 1.95	—	_	V <sub>CC</sub> ×0.3		
		2.3 to 2.7	—		0.7		
		3.0 to 3.6	—		0.8		
		Min to Max			0.2		I <sub>OL</sub> = 100 μA
		1.2			0.3		$I_{OL} = 2 \text{ mA}$
Output voltage	V <sub>OL</sub>	1.4			0.3	v	$I_{OL} = 4 \text{ mA}$
Oulput voltage	VOL	1.65			0.3	v	$I_{OL} = 6 \text{ mA}$
		2.3			0.55		I <sub>OL</sub> = 18 mA
		3.0			0.55		I <sub>OL</sub> = 24 mA
Input current	I <sub>IN</sub>	3.6			±5	μA	$V_{IN} = 3.6 V \text{ or GND}$
Off state output	l <sub>oz</sub>	3.6	_		±5	μA	V <sub>OUT</sub> = V <sub>CC</sub> or GND
Quiescent supply current	I <sub>CC</sub>	3.6	—	—	10	μA	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I <sub>OFF</sub>	0		_	5	μA	$V_{IN}$ or $V_O = 0$ to 3.6 V
Input capacitance	C <sub>IN</sub>	3.3		5.0		pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

# **Switching Characteristics**

$V_{CC} =$	1.2 V
• cc -	1.2 1

ltem Symbo		Та	= -40 to 85	5°C	Unit	Test Conditions	FROM	то
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	_	5.0	—	ns	C <sub>L</sub> = 15 pF	A	Ŧ

 $V_{CC} = 1.5 \pm 0.1 \text{ V}$ 

Item Symbo	Symbol	Та	= -40 to 8	5°C	Unit	Test Conditions	FROM	то
item	Symbol	Min	Min	Min	Unit		(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	1.0		7.0	ns	C <sub>L</sub> = 15 pF	А	Ϋ́

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$ 

ltem Symbol		Ta = -40 to 85°C			Unit	Test Conditions	FROM	то
nem	Symbol	Min	Тур	Max	Onit		(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	1.0	_	5.0	ns	C <sub>L</sub> = 30 pF	А	Ϋ́

 $V_{CC} = 2.5 \pm 0.2 V$ 

ltem	Item Symbol	Ta = -40 to 85°C			Unit	Test Conditions	FROM	то
item	Symbol	Min	Тур	Max	Unit	Test conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	0.5	_	3.5	ns	C <sub>L</sub> = 30 pF	А	Ŧ

 $V_{CC} = 3.3 \pm 0.3 V$ 

Itom Symbol		Ta = -40 to 85°C			Unit	Test Conditions	FROM	то
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	0.5	_	2.5	ns	C <sub>L</sub> = 30 pF	А	Ϋ́

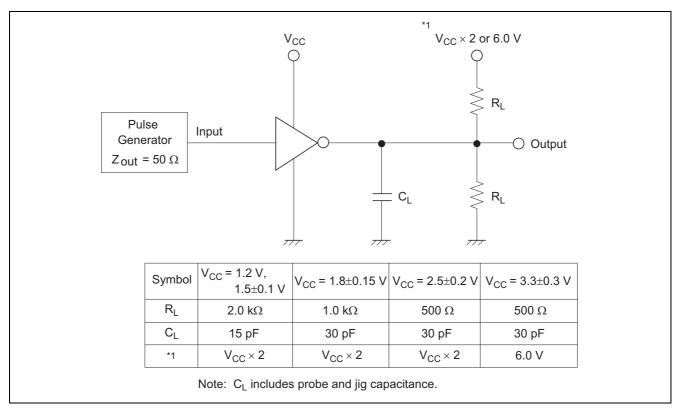
# **Operating Characteristics**

 $(Ta = 25^{\circ}C)$ 

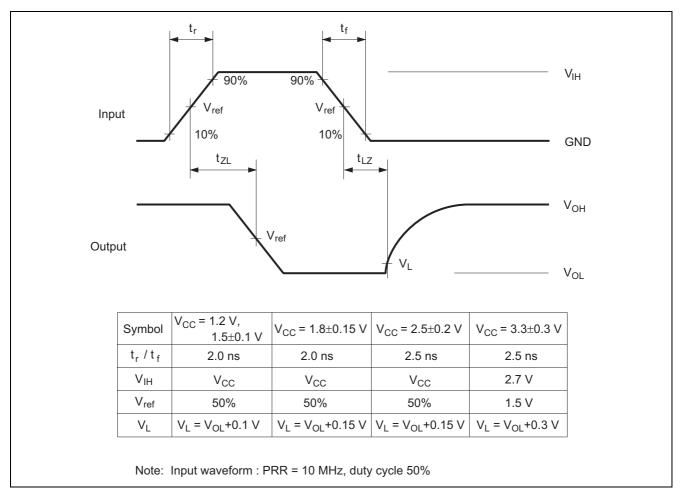
ltem	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test Conditions	
		1.5	_	1.5	—	- pF	f = 10 MHz	
Power dissipation	C <sub>PD</sub>	1.8	_	1.5	—			
capacitance	CPD	2.5	_	2.0	—			
		3.3		3.0	—			



# **Test Circuit**



### Waveforms





# Package Dimensions

JEITA Package Code	RENESAS Code Previous Code MASS[Typ.]		
P-VSSOP8-2.3x2-0.50	PVSP0008KA-A TTP-8DB/TTP-8DBV 0.010g		
		Image: break of the section         Terminal cross section         Image: break of the section	Reference Symbol         Dimension in Millimeters           Min         Nom         Max           D         1.8         2.0         2.2           E         2.2         2.3         2.4           A2         0.6         0.7         0.8           A1         0          0.1           A              bp         0.15         0.22         0.3           b1          0.20            C         0.08         0.13         0.23           C1          1.1 $\theta$ HE         2.8         3.1         3.4           [E]          (0.5)            X              Y              X              X              X              X              X



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